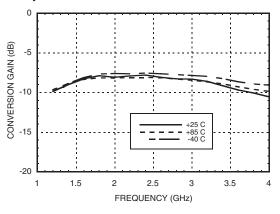
GaAs MMIC HIGH IP3 DOUBLE-BALANCED MIXER, 1.5 - 3.8 GHz



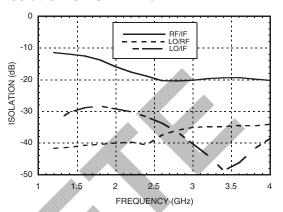
v02.0505



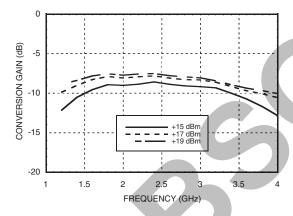
Conversion Gain vs. Temperature @ LO = +17 dBm



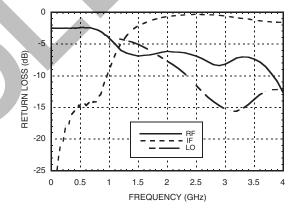
Isolation @ LO = +17 dBm



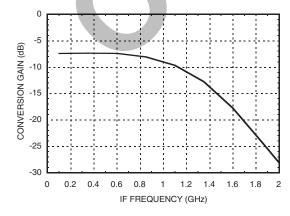
Conversion Gain vs. LO Drive



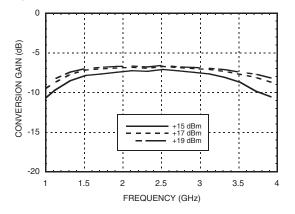
Return Loss @ LO = +17 dBm



If Bandwidth @ LO = +17 dBm



Upconverter Performance vs. LO Drive

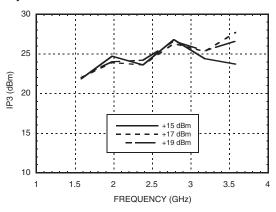




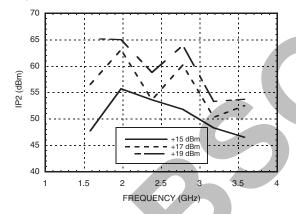
v02.0505



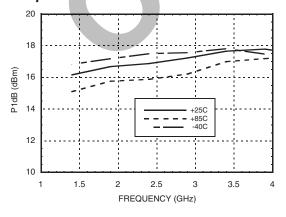
Input IP3 vs. LO Drive*



Input IP2 vs. LO Drive*

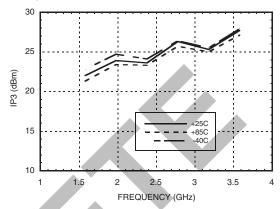


Input P1dB vs. Temperature @ LO = +17 dBm

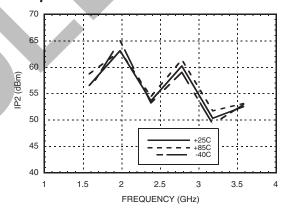


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Input IP3 vs. Temperature @ LO = +17dBm*



Input IP2 vs. Temperature @ LO = +17 dBm*



MxN Spurious Outputs

	nLO				
mRF	0	1	2	3	4
0	xx	-8	3.6	1.1	29
1	10	0	22	44	48
2	71	72	77	60	85
3	>110	>110	>110	91	91
4	>110	>110	>110	>110	>110

RF = 2.08 GHz @ -10 dBm LO = 1.9 GHz @ +17 dBm

All values in dBc relative to the IF output power.

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^{*} Two-tone input power = 0 dBm each tone, 1 MHz spacing.



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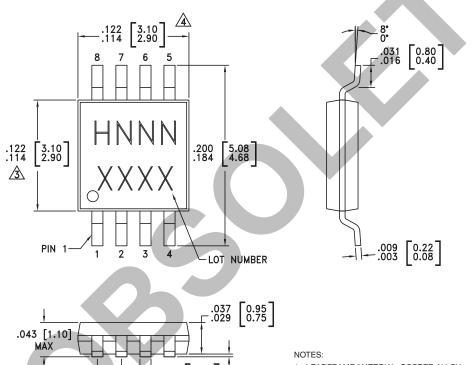
GaAs MMIC HIGH IP3 DOUBLE-BALANCED MIXER, 1.5 - 3.8 GHz

Absolute Maximum Ratings

RF / IF Input	+22 dBm	
LO Drive	+27 dBm	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	
IF DC Current	±18 mA	
ESD Sensitivity (HBM)	Class 1A	



Outline Drawing



- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 5. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

.0256 [0.65] TYP

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC316MS8	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H316 XXXX
HMC316MS8E	316MS8E RoHS-compliant Low Stress Injection Molded Plastic		MSL1 [2]	<u>H316</u> XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX

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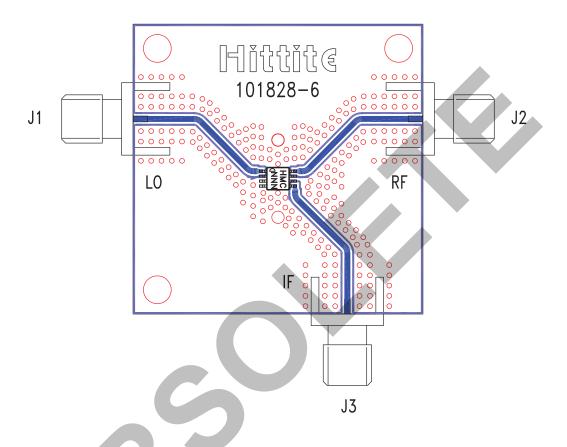


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GaAs MMIC HIGH IP3 DOUBLE-BALANCED MIXER, 1.5 - 3.8 GHz

Evaluation PCB



List of Materials for Evaluation PCB 101830 [1]

Item	Description
J1 - J3	PCB Mount SMA RF Connector
U1	HMC316MS8 / HMC316MS8E Mixer
PCB [2]	101828 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown below. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board as shown is available from Hittite upon request.



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Notes:

GaAs MMIC HIGH IP3 DOUBLE-BALANCED MIXER, 1.5 - 3.8 GHz

